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			Alessandro C. Callegari et al.					
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		U.S. PAT	ENT DOCUMENTS]
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OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)								
IBM Disclosure Bulletin, <u>Ion Bombardment of Polyimide for the Atignment of Liquid Crystals</u> , New York, Vol. 23, No. 4B, 9/1/91, pp. 80-82.								5ela
(-	Japanese Abstra	Japanese Abstract No. XP-002224303, 2/28/92) to Saiko Epson Curp for JP4063323A						
	U.S. Patent App Making a Crysta	U.S. Patent Application Publication No. 2002/0001057, Publication Date Jan. 3, 2002, Method and Apparatus for Making a Crystal Alignment Layer Chaudhari						
	U.S. Patent App INP-Based Mate	U.S. Patent Application Publication No. 2001/0025826, Publication Date Oct. 4, 2001, <u>Dense-Plasma Etching of INP-Based Materials Using Chlorine and Nitrogen</u> Pierson						
Thylo	U.S. Patent Application Publication No. 2001/0041380, Publication Date Nov. 15, 2001, Method for Forming a Multi-Domain Alignment Layer for a Liquid Crystal Display Device. \$\int a 177 a							٠
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